

High Performance Driver/Comparator, Active Load on a Single Chip

AD53509

FEATURES

250 MHz operation Driver/comparator and active load included **On-chip Schottky diode bridge** 52-lead LQFP_EP package

APPLICATIONS

Automatic test equipment (ATE) Semiconductor test systems **Board test systems** Instrumentation and characterization equipment

GENERAL DESCRIPTION

The AD53509 is a single chip that performs the pin electronics functions of driver, comparator, and active load in ATE VLSI and memory testers. In addition, a Schottky diode bridge for the active load and a VCOM buffer are included internally.

The driver is a proprietary design that features three active states: data high mode, data low mode, and term mode as well as an inhibit state. The output voltage range is -2 V to +7 V to accommodate a wide variety of test devices. The output leakage is typically <250 nA over the signal range.

The dual comparator, with an input range equal to the driver output range, features built-in latches and ECL-compatible outputs. The outputs are capable of driving 50 Ω signal lines terminated to -2 V. Signal tracking capability is >5 V/ns.

The active load can be set up to 40 mA load current with less than a 10 μ A linearity error through the set range. I_{OH}, I_{OL}, and the buffered VCOM are independently adjustable. On-board Schottky diodes provide high speed switching and low capacitance.

Also included on the chip is an on-board temperature sensor whose purpose is to give an indication of the surface temperature of the DCL. This information can be used to measure θ_{JC} and θ_{JA} or flag an alarm if proper cooling is lost. Output from the sensor is a current sink that is proportional to absolute temperature. The gain is trimmed to a nominal value of $1.0 \,\mu$ A/K. For example, the output current can be sensed by using a 10 k Ω resistor connected from 10 V to the THERM pin. A voltage drop across the resistor then develops that equals

 $10 \text{ K} \times 1 \mu \text{A/K} = 10 \text{ mV/K} = 2.98 \text{ V}$ (at room temperature)

FUNCTIONAL BLOCK DIAGRAM



Rev. B

Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.

TABLE OF CONTENTS

Features	. 1
Applications	. 1
General Description	. 1
Functional Block Diagram	. 1
Revision History	. 2
Specifications	. 3
Driver Specifications	. 3
Comparator Specifications	. 5

Active Load Specifications	6
Total Function Specifications	7
Absolute Maximum Ratings	8
ESD Caution	8
Pin Configuration and Function Descriptions	9
Outline Dimensions	11
Ordering Guide	11

REVISION HISTORY

3/08—Rev. A	A to Rev. B
-------------	-------------

Updated Format	Universal
Changes to Features and General Description	1
Changes to Table 1	3
Changes to Table 3	
Changes to Table 9	
Inserted Table 10	9
Updated Outline Dimensions	
Changes to Ordering Guide	

12/00—Rev. 0 to Rev. A

SPECIFICATIONS

DRIVER SPECIFICATIONS

All specifications are at $T_J = 85^{\circ}C \pm 5^{\circ}C$, $V_{CC} = 11 V \pm 3\%$, $V_{EE} = -6 V = \pm 3\%$, unless otherwise noted. All temperature coefficients are measured at $T_J = 75^{\circ}C$ to $95^{\circ}C$.

Parameter	Min	Тур	Max	Unit	Test Conditions
DIFFERENTIAL INPUT CHARACTERISTICS, DATA to DATA, IOD to IOD, RLD to RLD					
Input Voltage	-2		+3	V	
Differential Input Range			2	V	All digital inputs within a 2 V range
Bias Current	-250		+250	μA	$V_{IN} = -2 V_{r} + 3 V_{r}$
REFERENCE INPUTS					
Bias Currents	-50		+50	μΑ	$V_L, V_H, V_T = 5 V$
OUTPUT CHARACTERISTICS					
Logic High Range	-2		+7	V	Data = H, V_{H} = -2 V to +7 V, V_{L} = -2 V, V_{T} = 0 V
Logic Low Range	-2		+6	V	Data = L, V_L = -2 V to +6 V, V_H = 7 V, V_T = 0 V
Amplitude, V_H and V_L	0.1		9	V	$V_L = 0 V, V_H = 0.1 V, V_T = 0 V$
Absolute Accuracy					$V_L = -2 V, V_H = 7 V, V_T = 0 V$
V _H Offset	-50		+50	mV	Data = H, V_H = 0 V, V_L = -2 V, V_T = -1 V
V _H Gain + Linearity Error	0.3 – 5		0.3 + 5	% of $V_H + mV$	Data = H, V_{H} = -1 V to +7 V, V_{L} =-2 V, V_{T} = -2 V
V _L Offset	-50		+50	mV	Data = L, V_L = 0 V, V_H = 5 V, V_T = 3 V
V∟ Gain + Linearity Error	-0.3 - 5		+0.3 + 5	% of V _L + mV	Data = L, V_L = -2 V to +6 V, V_H = 7 V, V_T = 7 V
Offset Temperature Coefficient		0.5		mV/°C	$V_L = -2 V, V_H = 0 V, V_T = -1 V (V_H offset),$ $V_L = 0 V, V_H = 5 V, V_T = 3 V (V_L offset)$
Output Resistance					
$V_{H} = -2 V$	44	46	48	Ω	$V_L = -2 V, V_T = 0 V, I_{OUT} = 0 mA, 1 mA, 30 mA$
$V_H = +7 V$	44	46	48	Ω	$V_L = -1 V, V_T = 0 V, I_{OUT} = 0 mA, -1 mA, -30 mA$
$V_L = -2 V$	44	46	48	Ω	$V_{H} = 6 V, V_{T} = 0 V, I_{OUT} = 0 mA, 1, mA 30 mA$
$V_L = +6 V$	44	46	48	Ω	$V_H = 7 V, V_T = 0 V, I_{OUT} = 0 mA, -1 mA, -30 mA$
$V_H = +3 V$		46		Ω	$V_L = 0 V, V_T = 0 V, I_{OUT} = -30 \text{ mA}$ (trim point)
Dynamic Current Limit		>100		mA	$C_{BYP} = 39 \text{ nF}, V_H = 6 \text{ V}, V_L = -2 \text{ V}, V_T = 0 \text{ V}$
Static Current Limit	-85		+85	mA	Output to $-2 V$, $V_H = 7 V$, $V_L = -1 V$, $V_T = 0 V$, data = H and output to 7 V, $V_H = 6 V$, $V_L = -2 V$, $V_T = 0 V$, data = L
V _T					
Voltage Range	-2		+7	v	Term mode, $V_T = -2 V$ to $+7 V$, $V_L = 0 V$, $V_H = 3 V$
V _T Offset	-50		+50	mV	Term mode, $V_T = 0 V$, $V_L = 0 V$, $V_H = 3 V$
V⊤ Gain + Linearity Error	-0.3 + 10)	+0.3 + 10	% of V _{SET} + mV	Term mode, $V_T = -2 V$ to $+7 V$, $V_L = 0 V$, $V_H = 3 V$
Offset Temperature Coefficient		0.5		mV/°C	$V_T = 0 V, V_L = 0 V, V_H = 3 V$
Output Resistance	44	46	49	Ω	$ \begin{array}{l} I_{OUT} = 30 \text{ mA}, \ 1.0 \text{ mA}, \ V_T = -2.0 \text{ V}, \ V_H = 3 \text{ V}, \\ V_L = 0 \text{ V}, \ I_{OUT} = -30 \text{ mA}, \ -1.0 \text{ mA}, \ V_T = 7.0 \text{ V}, \\ V_H = 3 \text{ V}, \ V_L = 0 \text{ V}, \ I_{OUT} = \pm 30 \text{ mA}, \ \pm 1.0 \text{ mA}, \\ V_T = 0 \text{ V}, \ V_H = 3 \text{ V}, \ V_L = 0 \text{ V} \end{array} $
DYNAMIC PERFORMANCE, VH AND VL	1				
Propagation Delay Time		1.5		ns	Measured at 50%, $V_{\rm H}$ = 400 mV, $V_{\rm L}$ = –400 mV, $V_{\rm T}$ = 0 V
Propagation Delay Temperature Coefficient		2		ps/°C	Measured at 50%, $V_{\rm H}$ = 400 mV, $V_{\rm L}$ = -400 mV, $V_{\rm T}$ = 0 V
Delay Matching, Edge to Edge		<100		ps	Measured at 50%, $V_{\rm H}$ = 400 mV, $V_{\rm L}$ = -400 mV, $V_{\rm T}$ = 0 V

Parameter	Min Typ	Max	Unit	Test Conditions
Rise and Fall Times				
1 V Swing	0.42		ns	Measured 20% to 80%, V_L = 0 V, V_H = 1 V, V_T = 0 V
3 V Swing	0.75		ns	Measured 20% to 80%, V_L = 0 V, V_H = 3 V, V_T = 0 V
5 V Swing	1.65		ns	Measured 10% to 90%, V_L = 0 V, V_H = 5 V, V_T = 0 V
9 V Swing	3.0		ns	Measured 10% to 90%, $V_L=-2V,$ $V_H=7V,$ $V_T=0V$
Rise/Fall Time Temperature Coefficient				
1 V Swing	±1		ps/°C	Measured 20% to 80%, $V_L = 0 V$, $V_H = 1 V$
3 V Swing	±2		ps/°C	Measured 20% to 80%, $V_L = 0 V$, $V_H = 3 V$
5 V Swing	±4		ps/°C	Measured 10% to 90%, $V_L = 0 V$, $V_H = 5 V$
Overshoot and Preshoot	<3 + 50		% of Step + mV	$ \begin{aligned} V_L, V_H &= -0.1 \text{ V}, +0.1 \text{ V}, V_L, V_H &= 0 \text{ V}, +1.0 \text{ V} \\ V_L, V_H &= 0 \text{ V}, 3.0 \text{ V}, V_L, V_H &= 0 \text{ V}, 5.0 \text{ V} \\ V_L, V_H &= -2.0 \text{ V}, +7.0 \text{ V} \end{aligned} $
Settling Time				
to 15 mV	<50		ns	$V_{L} = 0 V, V_{H} = 0.5 V, V_{T} = -2 V$
to 4 mV	<10		μs	$V_L = 0 V, V_H = 0.5 V, V_T = -2 V$
Delay Change vs. Pulse Width	50		ps	$V_L = 0$ V, $V_H = 2$ V, pulse width = 2.5 ns/7.5 n 30 ns/90 ns
Minimum Pulse Width				
3 V Swing	1.4		ns	V_L = 0 V, V_H = 3 V, 90% (2.7 V) reached, measure @ 50%
5 V Swing	2.0		ns	V_L = 0 V, V_H = 5 V, 90% (4.5 V) reached, measure @ 50%
Toggle Rate	250		MHz	$V_L = 0 V, V_H = 5 V, VDUT > 3.0 V p-p$
DYNAMIC PERFORMANCE, INHIBIT				
Delay Time, Active to Inhibit	3.3		ns	Measured at 50%, $V_{H} = 2 V$, $V_{L} = -2 V$, $V_{T} = 0 V$
Delay Time, Inhibit to Active	2.9		ns	Measured at 50%, $V_{H} = 2 V$, $V_{L} = -2 V$, $V_{T} = 0 V$
Delay Time Matching, Z	<2		ns	Z = delay time, active to inhibit – delay time, inhibit to active (of worst two edges)
Input/Output Spike	150		mV p-p	$V_H = 0 V, V_L = 0 V, V_T = 0 V$
Rise/Fall Time, Active to Inhibit	1.6		ns	$V_{\rm H}$ = 2 V, $V_{\rm L}$ = -2 V (measured 20%/80% of 1 V output)
Rise/Fall Time, Inhibit to Active	1.4		ns	$V_{\rm H}$ = 2 V, $V_{\rm L}$ = -2 V (measured 20%/80% of 1 V output)
DYNAMIC PERFORMANCE, V _T				
Delay Time, V_{H} to V_{T} and V_{L} to V_{T}	2.5		ns	Measured at 50%, $V_L = -1 V$, $V_H = 1 V$, $V_T = 0 V$
Delay Time, V_T to V_H and V_T to V_L	2.5		ns	Measured at 50%, $V_L = V_H = 0.4 V$, $V_T = -0.4 V$
Overshoot and Preshoot	<3.0 + 75		% of Step + mV	V_H/V_L , $V_T = (0 V, -1 V)$, $(0 V, -2.0 V)$, $(0 V, +6.0 V)$
V⊤ Mode Rise Time	2.2		ns	$V_L = -2$ V, $V_H = 2$ V, $V_T = 0$ V, 20% to 80%
V_T Mode Fall Time	2.2		ns	$V_L = -2 V$, $V_H = 2 V$, $V_T = 0 V$, 20% to 80%
PSRR, Drive, or Term Mode	35		dB	$V_{S} = V_{S} \pm 3\%$

COMPARATOR SPECIFICATIONS

All specifications are at $T_J = 85^{\circ}C \pm 5^{\circ}C$. Outputs terminated in 150 Ω to GND, $V_{CC} = 11 \text{ V} \pm 3\%$, $V_{EE} = 6 \text{ V} \pm 3\%$, VCCO = 3.3 V, unless otherwise specified. All temperatures coefficients are measured at $T_J = 75^{\circ}C$ to 95°C.

Parameter	Min	Тур	Max	Unit	Test Conditions
DC INPUT CHARACTERISTICS					
Offset Voltage, Vos	-25		+25	mV	CMV = 0V
Offset Voltage, Drift		50		μV/°C	CMV = 0V
HCOMP, LCOMP Bias Current	-50		+50	μΑ	$V_{IN} = 0 V$
Voltage Range, V _{CM}	-2		+7.0	V	
Differential Voltage, VDIFF			9.0	V	
Gain and Linearity	-0.05		+0.05	% FSR	$V_{IN} = -2 V \text{ to } +7 V (9 V FSR)$
LATCH ENABLE INPUTS					
Logic 1 Current, I _{IH}			250	μΑ	LEA, $\overline{\text{LEA}}$, LEB, $\overline{\text{LEB}} = 3 \text{ V}$
Logic 0 Current, I	-250			μA	LEA, $\overline{\text{LEA}}$, LEB, $\overline{\text{LEB}} = -2 \text{ V}$
Logic Input Range	-2		+3	v	
DIGITAL OUTPUTS					
Logic 1 Voltage, V _{он}	VCCO – 0.98			V	Qx or \overline{Qx} , 16.7 mA load
Logic 0 Voltage, V _{ol}			VCCO – 1.5	v	Qx or \overline{Qx} , 10 mA load
Slew Rate		1		V/ns	
VCCO Range	0		8	V	
SWITCHING PERFORMANCE					
Propagation Delay					
Input to Output		1.8		ns	V _{IN} = 2 V p-p
Latch Enable to Output		2		ns	HCOMP = 1 V, LCOMP = 1 V
Propagation Delay Temperature Coefficient		2		ps/°C	
Propagation Delay Change with Respect to					
Slew Rate: 0.5 V/ns, 1.0 V/ns, 3.0 V/ns		<±100		ps	$V_{IN} = 0 V \text{ to } 5 V$
Slew Rate: 5.0 V/ns		<±350		ps	$V_{IN} = 0 V \text{ to } 5 V$
Amplitude: 1.0 V, 3.0 V, 5.0 V		<±200		ps	$V_{IN} = 1.0 \text{ V/ns}$
Equivalent Input Rise Time		450		ps	$V_{IN} = 0 V$ to 3 V, 3 V/ns
Pulse Width Linearity		<±200		ps	$V_{IN} = 0 V$ to 3 V, 3 V/ns, PW = 3 ns to 8 ns
Settling Time		25		ns	Settling to $\pm 8 \text{ mV}$, $V_{IN} = 1 \text{ V}$ to 0 V
Latch Timing					_
Input Pulse Width		1.68		ns	
Setup Time		1.0		ns	
Hold Time		1.1		ns	
Hysteresis		6		mV	Latch inputs programmed for hysteresi

ACTIVE LOAD SPECIFICATIONS

All specifications are at $T_I = 85^{\circ}C \pm 5^{\circ}C$, $V_{CC} = 11 \text{ V} \pm 3\%$, $V_{EE} = -6 \text{ V} = \pm 3\%$, unless otherwise noted. All temperature coefficients are measured at $T_I = 75^{\circ}C$ to $95^{\circ}C$.

Table 3.					
Parameter	Min	Тур	Max	Unit	Test Conditions
INPUT CHARACTERISTICS					
INHL, INHL					
Input Voltage	-2		+3	V	$IOHC = 1 V, IOLC = 1 V, VCOM = 2 V, OUT_L = 0 V$
Bias Current	-250		+250	μA	$INHL, \overline{INHL} = -2 V, +3 V$
IOHC Current Program Range					
IOH = 0 mA to -40 mA	0		4	v	OUT_L = -0.7 V, +7 V
IOLC Current Program Range					
IOL = 0 mA to 40 mA	0		4	V	OUT_L = -2 V, +5.7 V
IOHC, IOLC Input Bias Current	-300		+300	μΑ	IOLC = 0 V, 4.0 V and IOHC = 0 V, 4.0 V
IOLRTN, IOHRTN Range	-2		+7	V	$IOL = 40 \text{ mA}, IOH = -40 \text{ mA}, OUT_L = -2 \text{ V}, +7 \text{ V}$
VDUT Range	-2		+7	V	IOL = 40 mA, IOH = -40 mA, OUT_L - VCOMI > 1.3 V
VDUT Range, IOH = 0 mA to -40 mA	-0.7		+7	V	OUT_L – VCOM > 1.3 V
VDUT Range, IOL = 0 mA to 40 mA	-2		+5.7	V	VCOM – VDUT > 1.3 V
VCOMI Input Range	-2		+7	V	IOL = 40 mA, IOH = -40 mA
OUTPUT CHARACTERISTICS					
Accuracy					
Absolute Accuracy Error, Load Current	-0.3 - 100		+0.3 + 100	% Iset + μA	IOL, IOH = 25 μ A to 40 mA, VCOM = 0 V, OUT_L = ± 2 V and IOL = 25 μ A to 40 mA, VCOM = 7 V, OUT_L = 5.7 V and IOH = 25 μ A to 40 mA, VCOM = -2 V, OUT_L = -0.7 V
VCOM Buffer					
Offset Error	-50		+50	mV	IOL , $IOH = 40 \text{ mA}$, $VCOMI = 0 \text{ V}$, $OUT_L = VCOM$
Bias Current	-10	+1	+10	μΑ	VCOMI = 0 V, OUT_L = VCOM
Gain Error	-0.2		+0.2	%	IOL, IOH = 40 mA, VCOMI = -1 V to $+6$ V, V _{OUT} = VCOM
Linearity Error	-10		+10	mV	IOL, IOH = 40 mA, VCOMI = -1 V to $+6$ V, V _{OUT} = VCOM
Output Current Temperature Coefficient		<±2		μA/°C	Measured at IOH, IOL = 200 μA
DYNAMIC PERFORMANCE					
Propagation Delay					
±lout to Inhibit		1.9		ns	$VCOM = \pm 2 V$, $IOL = 20 mA$, $IOH = -20 mA$
Inhibit to ±I _{OUT}		2.8		ns	$VCOM = \pm 2 V$, $IOL = 20 mA$, $IOH = 20 mA$
Propagation Delay Matching		<1.8		ns	
Input/Output Spike		240		mV	VCOM = 0 V, IOL = 20 mA, IOH = -20 mA
Settling Time to 15 mV		<50		ns	IOL = 20 mA, IOH = -20 mA, 50Ω load to ± 15 mV
Settling Time to 4 mV		<10		μs	IOL = 20 mA, IOH = -20 mA, 50 Ω load to ± 4 mV

TOTAL FUNCTION SPECIFICATIONS

All specifications are at $T_I = 85^{\circ}C \pm 5^{\circ}C$, $V_{CC} = 11 V \pm 3\%$, $V_{EE} = -6 V = \pm 3\%$ unless otherwise noted. All temperature coefficients are measured at $T_I = 75^{\circ}C$ to $95^{\circ}C$.

Parameter ¹	Min	Тур	Max	Unit	Test Conditions
OUTPUT CHARACTERISTICS					
Output Leakage Current, $V_{OUT} = -1 V$ to +5 V	-250		+250	nA	
Output Leakage Current, $V_{OUT} = -2 V$ to $+7 V$	-500		+500	μΑ	
Output Capacitance		8		рF	Driver and load inhibited
POWER SUPPLIES					
Total Supply Range		17		V	
Positive Supply, V _{CC}		11		V	
Negative Supply, VEE		-6		V	
Positive Supply Current			280	mA	Driver = I_{NH} , I_{LOAD} program = 40 mA, load = active
Negative Supply Current			290	mA	Driver = I_{NH} , I_{LOAD} program = 40 mA, load = active
VCCO Current		65		mA	VCCO = 3.3 V, comparator output 150 Ω to GND
Total Power Dissipation			4.8	W	Driver = I_{NH} , I_{LOAD} program = 40 mA, load = active
Temperature Sensor Gain Factor		1		μA/K	$R_{LOAD} = 10 \text{ k}\Omega, V_{SOURCE} = 11 \text{ V}$

 $^{\rm 1}$ Connecting or shorting the decoupling pins to ground results in the destruction of the device.

Table 5. Driver Truth Table

DATA	DATA	IOD	IOD	RLD	RLD	Output State					
0	1	1	0	Х	Х	VL					
1	0	1	0	Х	Х	V _H					
Х	Х	0	1	0	1	Inhibit					
Х	Х	0	1	1	0	VT					

Table 6. Comparator Truth Table

						Output States			
	Vout	LEH	LEH	LEL	LEL	QH	QH	QL	QL
>HCOMP	>LCOMP	1	0	1	0	1	0	1	0
>HCOMP	<lcomp< td=""><td>1</td><td>0</td><td>1</td><td>0</td><td>1</td><td>0</td><td>0</td><td>1</td></lcomp<>	1	0	1	0	1	0	0	1
<hcomp< td=""><td>>LCOMP</td><td>1</td><td>0</td><td>1</td><td>0</td><td>0</td><td>1</td><td>1</td><td>0</td></hcomp<>	>LCOMP	1	0	1	0	0	1	1	0
<hcomp< td=""><td><lcomp< td=""><td>1</td><td>0</td><td>1</td><td>0</td><td>0</td><td>1</td><td>0</td><td>1</td></lcomp<></td></hcomp<>	<lcomp< td=""><td>1</td><td>0</td><td>1</td><td>0</td><td>0</td><td>1</td><td>0</td><td>1</td></lcomp<>	1	0	1	0	0	1	0	1
Х	Х	0	1	0	1	QH (t – 1)	QH (t – 1)	QL (t – 1)	<u>QL</u> (t – 1)

Table 7. Active Load Truth Table

OUT_L	INHL		Outpu	Output States (Including Diode Bridge)		
		INHL	ЮН	IOL	I(OUT_L)	
<vcom< td=""><td>0</td><td>1</td><td>V(IOHC) × 10 mA</td><td>V(IOLC) × 10 mA</td><td>IOL</td></vcom<>	0	1	V(IOHC) × 10 mA	V(IOLC) × 10 mA	IOL	
>VCOM	0	1	V(IOHC) × 10 mA	$V(IOLC) \times 10 \text{ mA}$	IOH	
Х	1	0	0	0	0	

ABSOLUTE MAXIMUM RATINGS

Table 8.

Power Supply Voltage $-$ Vcc to GND13 VVEE to GND-8 VVcc to VEE20 VVCCO to GND10 VPWRGND, HQGND, HQGND2±0.4 VInputs-2 V to +5 VDATA, DATA, IOD, IOD, RLD, RLD±3 VLEL, LEL, LEH, LEH-2 V to +5 VLEL, TEL, LEH, LEH+3 VINHL, INHL-2 V to +5 VINHL, NHL+3 VVH, V, V, V, VCOMI to GND-3 V to +8 VVH to VL±10 VIOHC±6 VIOLC±6 VHCOMP-3 V to +8 VLCOMP-3 V to +8 VUty to VL±10 VVour Short-Circuit DurationIndefinite ¹ Vour Inhibit Mode-3 V to +8 VVHDCPLDo not connect exceptfor capacitor to V _{CC} Do not connect exceptfor capacitor to V _{CC} Do not connect exceptQH, QH, QL, QL Maximum lour50 mAContinuous50 mASurge100 mATHERM0 V to 13 VIOHRTN, IOLRTN-3.5 V to +8.5 VVCOMS Short-Circuit Duration3 sec ¹ EnvironmentalOperating Temperature (Junction)175°C175°C					
Vcc to GND13 V V_{EE} to GND -8 V V_{CC} to V_{EE} 20 VVCCO to GND10 VPWRGND, HQGND, HQGND2 ± 0.4 VInputs -2 V to $+5$ VDATA, DATA, IOD, IOD, RLD, RLD ± 3 VLEL, LEL, LEH, LEH ± 3 VLEL, LEL, LEH, LEH ± 3 VINHL, INHL -2 V to $+5$ VINHL, V, V, V, VCOMI to GND ± 3 VV _H , V _L , V, T, VCOMI to GND -3 V to $+8$ VVH to VL ± 10 VIOHC ± 6 VIOLC ± 6 VHCOMP -3 V to $+8$ VLCOMP -3 V to $+8$ VLCOMP -3 V to $+8$ VVHCOMP -3 V to $+8$ VLCOMP -3 V to $+8$ VDOUT -3 V to $+8$ VDUT -3 V to $+8$ VDUT -3 V to $+8$ VDOILC -3 V to $+8$ VDOUT -3 V to $+8$ VDOILC -3 V to	Parameter	Rating			
VEE to GND-8 VVCc to VEE20 VVCCO to GND10 VPWRGND, HQGND, HQGND2 ± 0.4 VInputs ± 0.4 VDATA, DATA, IOD, IOD, RLD, RLD ± 3 VLEL, LEL, LEH, LEH ± 3 VLEL, TEL, LEH, LEH ± 3 VINHL, INHL -2 V to $+5$ VINHL to INHL ± 3 VVH, VL, VT, VCOMI to GND -3 V to $+8$ VVH to VL ± 10 V(VH - VT) and (VT - VL) ± 10 VIOHC ± 6 VHCOMP -3 V to $+8$ VLCOMP -3 V to $+8$ VHCOMP, LCOMP to VouT ± 10 VVout Short-Circuit DurationIndefinite ¹ Vout Short-Circuit DurationIndefinite ¹ VHDCPL 50 mAOH, QH, QL, QL Maximum louT 50 mAContinuous 50 mASurge 100 mATHERM 0 V to 13 VIOHRTN, IOLRTN -3.5 V to $+8.5$ VVCOMS Short-Circuit Duration 3 sec ¹ IOHRTN, IOLRTN -3.5 V to $+8.5$ VVCOMS Short-Circuit Duration 3 sec ¹					
V_{CC} to V_{EE} 20 V $VCCO$ to GND10 V $PWRGND, HQGND, HQGND2$ ± 0.4 VInputs ± 0.4 V $DATA, DATA, IOD, IOD, RLD, RLD\pm 3 VLEL, LEL, LEH, LEH\pm 3 VLEL, IEL, LEH, LEH\pm 3 VIEL to IEL, LEH to IEH\pm 3 VINHL, INHL\pm 3 VV_{H}, V_L, V_T, VCOMI to GND-3 V to +5 VV_{H} to V_L\pm 10 VV_{T} ond (V_T - V_L)\pm 10 VVOLC\pm 6 VVOUT Short-Circuit Duration-3 V to +8 VV_{OUT} Unbibit Mode-3 V to +8 VV_{DCPL}Do not connect exceptV_{H} QH, QL, QL Maximum lour50 mASurge100 mATHERM0 V to 13 VIOHRTN, IOLRTN-3.5 V to +8.5 VVCOMS Short-Circuit Duration-3.5 V to +8.5 VVCOMS Short-Circuit Duration3 sec'Internal0 V to 13 VOperating Temperature (Junction)175^{\circ}C$	V _{cc} to GND	-			
VCCO to GND10 VPWRGND, HQGND, HQGND2±0.4 VInputs-2 V to +5 VDATA, DATA, IOD, IOD, RLD, RLD±3 VLEL, LEL, LEH, LEH±3 VLEL, LEL, LEH, LEH±3 VINHL, INHL-2 V to +5 VINHL to INHL±3 VVH, VL, VT, VCOMI to GND-3 V to +5 VUCOMP±10 VVH to VL±10 VVH to VL±10 VIOHC±6 VIOLC±6 VHCOMP-3 V to +8 VLCOMP-3 V to +8 VUNT short-Circuit DurationIndefinite1Vout Short-Circuit DurationIndefinite1VUDCPL50 mAQH, QH, QL, QL Maximum lout50 mAContinuous50 mASurge100 mAIOHRTN, IOLRTN-3.5 V to +8.5 VSocods Short-Circuit Duration0 V to 13 VIOHRTN, IOLRTN-3.5 V to +8.5 VSocods Short-Circuit Duration100 mATHERM0 V to 13 VIOHRTN, IOLRTN-3.5 V to +8.5 VSocods Short-Circuit Duration3 sec1Environmental0Operating Temperature (Junction)175°C	V _{EE} to GND	-8 V			
PWRGND, HQGND, HQGND2 $\pm 0.4 V$ Inputs $-2 V to +5 V$ DATA, DATA, IOD, IOD, RLD, RLD $-2 V to +5 V$ DATA to DATA, IOD to IOD, RLD to RLD $\pm 3 V$ LEL, LEL, LEH, LEH $-2 V to +5 V$ LEL to LEL, LEH to LEH $\pm 3 V$ INHL, INHL $-2 V to +5 V$ INHL to INHL $\pm 3 V$ VH, VL, VT, VCOMI to GND $-3 V to +8 V$ VH to VL $\pm 10 V$ IOHC $\pm 6 V$ IOLC $\pm 6 V$ HCOMP $-3 V to +8 V$ LCOMP $-3 V to +8 V$ VOUT Short-Circuit DurationIndefinite'VUDCPL $-3 V to +8 V$ VHDCPL $-3 V to +8 V$ VHDCPL $-3 V to +8 V$ VLDCPL $-3 V to +8 V$ Out, Guinuous $50 mA$ Surge $100 mA$ THERM $0 V to 13 V$ IOHRTN, IOLRTN $-3.5 V to +8.5 V$ VCOMS Short-Circuit Duration $-3.5 V to +8.5 V$ Outputs $50 mA$ Do not connect except for capacitor to VEEDATA Surge $100 mA$ IOHRTN, IOLRTN $-3.5 V to +8.5 V$ VCOMS Short-Circuit Duration $3 sec'$	V _{CC} to V _{EE}	20 V			
Inputs-2 V to +5 VDATA, DATA, IOD, IOD, RLD, RLD-2 V to +5 VDATA to DATA, IOD to IOD, RLD to RLD±3 VLEL, LEL, LEH, LEH-2 V to +5 VLEL to IEL, LEH to LEH±3 VINHL, INHL-2 V to +5 VINHL to INHL±3 VV _H , V _L , V _T , VCOMI to GND-3 V to +8 VV _H to VL±10 V(V _H - V _T) and (V _T - V _L)±10 VIOHC±6 VIOLC±6 VHCOMP-3 V to +8 VLCOMP-3 V to +8 VUoty to Short-Circuit DurationIndefinite¹Vout Short-Circuit DurationIndefinite¹VLDCPLDo not connect except for capacitor to V _{CE} QH, QH, QL, QL Maximum lout50 mASurge100 mAIOHRTN, IOLRTN-3.5 V to +8.5 VVCOMS Short-Circuit Duration3 sec¹IOHRTN, IOLRTN3 sec¹IOHRTN, IOLRTN175°C	VCCO to GND	10 V			
DATA, DATA, IOD, IOD, RLD, RLD $-2 V to +5 V$ DATA to DATA, IOD to IOD, RLD to RLD $\pm 3 V$ LEL, LEL, LEH, LEH $-2 V to +5 V$ LEL to IEL, LEH to LEH $\pm 3 V$ INHL, INHL $-2 V to +5 V$ INHL to INHL $\pm 3 V$ $V_H, V_L, V_T, VCOMI to GND$ $-3 V to +8 V$ $V_H to V_L$ $\pm 10 V$ $V_H + V_1$ and $(V_T - V_L)$ $\pm 10 V$ $IOHC$ $\pm 6 V$ $IOLC$ $\pm 6 V$ $ICOMP$ $-3 V to +8 V$ $LCOMP$ $-3 V to +8 V$ $Uoty$ to V_{0UT} $\pm 10 V$ V_{0UT} short-Circuit DurationIndefinite' V_{0UT} Inhibit Mode $-3 V to +8 V$ $VLDCPL$ Do not connect except for capacitor to V_{CC} $QH, QH, QL, QL Maximum louT$ $50 mA$ $Surge$ $100 mA$ $IOHRTN, IOLRTN$ $-3.5 V to +8.5 V$ $VCOMS Short-Circuit Duration$ $-3.5 V to +8.5 V$ $VCOMS Short-Circuit Duration$ $175^{\circ}C$	PWRGND, HQGND, HQGND2	±0.4 V			
DATA to DATA, IOD to IOD, RLD to RLD ± 3 VLEL, LEL, LEH, LEH -2 V to $+5$ VLEL to LEL, LEH to LEH ± 3 VINHL, INHL -2 V to $+5$ VINHL to INHL ± 3 VVH, VL, VT, VCOMI to GND -3 V to $+8$ VVH to VL ± 10 V(V _H - VT) and (VT - VL) ± 10 VIOHC ± 6 VIOLC ± 6 VHCOMP -3 V to $+8$ VLCOMP -3 V to $+8$ VHCOMP, LCOMP to VouT ± 10 VOutputs -3 V to $+8$ VVHDCPLDo not connect except for capacitor to VccVLDCPLDo not connect except for capacitor to VEEQH, QH, QL, QL Maximum IouT50 mASurge100 mATHERM0 V to 13 VIOHRTN, IOLRTN -3.5 V to $+8.5$ VVCOMS Short-Circuit Duration 3 sec1INHRN 175° C	·				
LEL, \overline{LEL} , \overline{LEH} , \overline{LEH} $-2 V \text{ to } +5 V$ LEL to \overline{LEL} , LEH to \overline{LEH} $\pm 3 V$ INHL, \overline{INHL} $-2 V \text{ to } +5 V$ INHL to \overline{INHL} $\pm 3 V$ $V_H, V_L, V_T, VCOMI to GND$ $-3 V \text{ to } +8 V$ $V_H, V_L, V_T, VCOMI to GND$ $-3 V \text{ to } +8 V$ $V_H, V_L, V_T, VCOMI to GND$ $-3 V \text{ to } +8 V$ $V_H to V_L$ $\pm 10 V$ $(V_H - V_T)$ and $(V_T - V_L)$ $\pm 10 V$ IOHC $\pm 6 V$ IOLC $\pm 6 V$ HCOMP $-3 V \text{ to } +8 V$ LCOMP $-3 V \text{ to } +8 V$ LCOMP $-3 V \text{ to } +8 V$ VOUT Short-Circuit DurationIndefinite ¹ V_{OUT} Inhibit Mode $-3 V \text{ to } +8 V$ VHDCPLDo not connect except for capacitor to V_{CC} VLDCPLDo not connect except for capacitor to V_{EE} QH, \overline{QH} , QL, \overline{QL} Maximum lout 50 mA Surge100 mATHERM0 V to 13 VIOHRTN, IOLRTN $-3.5 V \text{ to } +8.5 V$ VCOMS Short-Circuit Duration $3 \sec^1$ Environmental $Operating Temperature (Junction)$ $0 perating Temperature (Junction)$ $175^{\circ}C$	DATA, DATA, IOD, IOD, RLD, RLD	-2 V to +5 V			
LEL to \overline{LEL} , LEH to \overline{LEH} $\pm 3 V$ INHL, \overline{INHL} $-2 V$ to $+5 V$ INHL to \overline{INHL} $\pm 3 V$ $V_H, V_L, V_T, VCOMI to GND$ $-3 V$ to $+8 V$ $V_H, V_L, V_T, VCOMI to GND$ $-3 V$ to $+8 V$ V_H to V_L $\pm 10 V$ $(V_H - V_T)$ and $(V_T - V_L)$ $\pm 10 V$ IOHC $\pm 6 V$ IOLC $\pm 6 V$ HCOMP $-3 V$ to $+8 V$ LCOMP $-3 V$ to $+8 V$ LCOMP $-3 V$ to $+8 V$ VOUT Short-Circuit DurationIndefinite ¹ V_{0UT} Inhibit Mode $-3 V$ to $+8 V$ VHDCPLDo not connect except for capacitor to V_{CC} VLDCPLDo not connect except for capacitor to V_{EE} QH, \overline{QH} , QL, \overline{QL} Maximum lout 50 mA Surge100 mATHERM $0 V$ to $13 V$ IOHRTN, IOLRTN $-3.5 V$ to $+8.5 V$ VCOMS Short-Circuit Duration $3 \sec^1$ Environmental $-3.5 °C$	DATA to $\overline{\text{DATA}}$, IOD to $\overline{\text{IOD}}$, RLD to $\overline{\text{RLD}}$	±3 V			
INHL, \overline{INHL} $-2 V \text{ to } +5 V$ INHL to \overline{INHL} $\pm 3 V$ $V_H, V_L, V_T, VCOMI to GND$ $-3 V \text{ to } +8 V$ $V_H to V_L$ $\pm 10 V$ $(V_H - V_T) \text{ and } (V_T - V_L)$ $\pm 10 V$ $IOHC$ $\pm 6 V$ $IOLC$ $\pm 6 V$ $HCOMP$ $-3 V \text{ to } +8 V$ $LCOMP$ $-3 V \text{ to } +8 V$ $LCOMP$ $-3 V \text{ to } +8 V$ $VOUT$ Short-Circuit DurationIndefinite ¹ V_{OUT} Inhibit Mode $-3 V \text{ to } +8 V$ $VLDCPL$ Do not connect except for capacitor to V_{CC} $VLDCPL$ Do not connect except for capacitor to V_{EE} $QH, \overline{QH}, QL, \overline{QL}$ Maximum lout 50 mA $Surge$ 100 mA $THERM$ $0 V \text{ to } 13 V$ $IOHRTN, IOLRTN$ $-3.5 V \text{ to } +8.5 V$ $VCOMS$ Short-Circuit Duration 3 sec^1 $Environmental$ $0 \text{ perating Temperature (Junction)}$ $0 \text{ perating Temperature (Junction)}$ $175^{\circ}C$	LEL, <u>LEL</u> , LEH, <u>LEH</u>	-2 V to +5 V			
INHL to \overline{INHL} $\pm 3 V$ $V_{H_r} V_{L_r} V_{T_r} VCOMI to GND$ $-3 V to +8 V$ $V_{H} to V_{L}$ $\pm 10 V$ $(V_{H} - V_{T}) and (V_{T} - V_{L})\pm 10 VIOHC\pm 6 VIOLC\pm 6 VHCOMP-3 V to +8 VLCOMP-3 V to +8 VLCOMP-3 V to +8 VVOUT Short-Circuit DurationIndefinite1V_{0UT} Inhibit Mode-3 V to +8 VVHDCPLDo not connect except for capacitor to V_{CC}VLDCPLDo not connect except for capacitor to V_{EE}QH, \overline{QH}, QL, \overline{QL} Maximum lout50 mASurge100 mATHERM0 V to 13 VIOHRTN, IOLRTN-3.5 V to +8.5 VVCOMS Short-Circuit Duration3 \sec^{-1}Environmental0Operating Temperature (Junction)175^{\circ}C$	LEL to LEL, LEH to LEH	±3 V			
VH, VL, VT, VCOMI to GND $-3 V$ to $+8 V$ VH, VL, VT, VCOMI to GND $-3 V$ to $+8 V$ VH to VL $\pm 10 V$ $(V_H - V_T)$ and $(V_T - V_L)$ $\pm 10 V$ $IOHC$ $\pm 6 V$ $IOLC$ $\pm 6 V$ $HCOMP$ $-3 V$ to $+8 V$ $LCOMP$ $-3 V$ to $+8 V$ $HCOMP, LCOMP$ to V_{OUT} $\pm 10 V$ Outputs $10 V$ V_{OUT} Short-Circuit DurationIndefinite ¹ V_{OUT} Inhibit Mode $-3 V$ to $+8 V$ $VHDCPL$ Do not connect except for capacitor to V_{CC} $VLDCPL$ Do not connect except for capacitor to V_{EE} $QH, \overline{QH}, QL, \overline{QL}$ Maximum lout $50 mA$ $Surge$ $100 mA$ $THERM$ $0 V$ to $13 V$ $IOHRTN, IOLRTN$ $-3.5 V$ to $+8.5 V$ $VCOMS$ Short-Circuit Duration $3 sec^1$ Environmental 0 perating Temperature (Junction) $175^{\circ}C$ $175^{\circ}C$	INHL, INHL	-2 V to +5 V			
VH to V_L $\pm 10 V$ $(V_H - V_T)$ and $(V_T - V_L)$ $\pm 10 V$ $IOHC$ $\pm 6 V$ $IOLC$ $\pm 6 V$ $IOLC$ $\pm 6 V$ $HCOMP$ $-3 V to +8 V$ $LCOMP$ $-3 V to +8 V$ $HCOMP, LCOMP to V_{OUT}$ $\pm 10 V$ Outputs $10 V$ V_{OUT} Short-Circuit DurationIndefinite ¹ V_{OUT} Inhibit Mode $-3 V to +8 V$ $VHDCPL$ Do not connect except for capacitor to V_{CC} $VLDCPL$ Do not connect except for capacitor to V_{EE} $QH, \overline{QH}, QL, \overline{QL}$ Maximum lout50 mA $Surge$ 100 mA $THERM$ $0 V to 13 V$ $IOHRTN, IOLRTN$ $-3.5 V to +8.5 V$ $VCOMS$ Short-Circuit Duration $3 \sec^1$ Environmental 0 perating Temperature (Junction) $175^{\circ}C$ $175^{\circ}C$	INHL to INHL	±3 V			
Index ± 10 V $(V_H - V_T)$ and $(V_T - V_L)$ ± 10 V $IOHC$ ± 6 V $IOLC$ ± 6 V $HCOMP$ -3 V to $+8$ V $LCOMP$ -3 V to $+8$ V $HCOMP, LCOMP$ to V_{OUT} ± 10 VOutputs 10 V V_{OUT} Short-Circuit DurationIndefinite ¹ V_{OUT} Inhibit Mode -3 V to $+8$ VVHDCPLDo not connect except for capacitor to V _{CC} VLDCPLDo not connect except for capacitor to V _{EE} QH, $\overline{QH}, QL, \overline{QL}$ Maximum lout50 mASurge100 mATHERM0 V to 13 VIOHRTN, IOLRTN -3.5 V to $+8.5$ VVCOMS Short-Circuit Duration3 sec ¹ EnvironmentalOperating Temperature (Junction)0Prior175°C	V_H , V_L , V_T , VCOMI to GND	−3 V to +8 V			
IOHC±6 VIOLC±6 VHCOMP-3 V to +8 VLCOMP-3 V to +8 VHCOMP, LCOMP to Vout±10 VOutputs10 VVout Short-Circuit DurationIndefinite1Vout Inhibit Mode-3 V to +8 VVHDCPLDo not connect except for capacitor to VccVLDCPLDo not connect except for capacitor to VccQH, QH, QL, QL Maximum lout50 mASurge100 mATHERM0 V to 13 VIOHRTN, IOLRTN-3.5 V to +8.5 VVCOMS Short-Circuit Duration3 sec1Environmental0Operating Temperature (Junction)175°C	V_H to V_L	±10 V			
IOLC±6 VIOLC±6 VHCOMP-3 V to +8 VLCOMP-3 V to +8 VHCOMP, LCOMP to Vout±10 VOutputsIndefinite1Vout Short-Circuit DurationIndefinite1Vout Inhibit Mode-3 V to +8 VVHDCPLDo not connect except for capacitor to VccVLDCPLDo not connect except for capacitor to VccQH, QH, QL, QL Maximum lout50 mASurge100 mATHERM0 V to 13 VIOHRTN, IOLRTN-3.5 V to +8.5 VVCOMS Short-Circuit Duration3 sec1Environmental0perating Temperature (Junction)175°C	$(V_H - V_T)$ and $(V_T - V_L)$	±10 V			
HCOMP-3 V to +8 VLCOMP-3 V to +8 VHCOMP, LCOMP to Vout±10 VOutputs-3 V to +8 VVout Short-Circuit DurationIndefinite1Vout Inhibit Mode-3 V to +8 VVHDCPLDo not connect except for capacitor to VccVLDCPLDo not connect except for capacitor to VEEQH, QH, QL, QL Maximum lout50 mASurge100 mATHERM0 V to 13 VIOHRTN, IOLRTN-3.5 V to +8.5 VVCOMS Short-Circuit Duration3 sec1Environmental175°C	IOHC	±6 V			
LCOMP-3 V to +8 VHCOMP, LCOMP to Vout±10 VOutputsIndefinite1Vout Short-Circuit DurationIndefinite1Vout Inhibit Mode-3 V to +8 VVHDCPLDo not connect except for capacitor to VccVLDCPLDo not connect except for capacitor to VcEQH, QH, QL, QL Maximum lout50 mASurge100 mATHERM0 V to 13 VIOHRTN, IOLRTN-3.5 V to +8.5 VVCOMS Short-Circuit Duration3 sec1Environmental175°C	IOLC	±6 V			
HCOMP, LCOMP to Vout±10 VOutputsIndefinite1Vout Short-Circuit DurationIndefinite1Vout Inhibit Mode-3 V to +8 VVHDCPLDo not connect except for capacitor to VccVLDCPLDo not connect except for capacitor to VccQH, QH, QL, QL Maximum lout50 mASurge100 mATHERM0 V to 13 VIOHRTN, IOLRTN-3.5 V to +8.5 VVCOMS Short-Circuit Duration3 sec1Environmental0perating Temperature (Junction)175°C	HCOMP	−3 V to +8 V			
OutputsIndefinite1Vout Short-Circuit DurationIndefinite1Vout Inhibit Mode-3 V to +8 VVHDCPLDo not connect except for capacitor to VccVLDCPLDo not connect except for capacitor to VccQH, QH, QL, QL Maximum lout50 mASurge100 mATHERM0 V to 13 VIOHRTN, IOLRTN-3.5 V to +8.5 VVCOMS Short-Circuit Duration3 sec1Environmental175°C	LCOMP	−3 V to +8 V			
Vout Short-Circuit DurationIndefinite1Vout Inhibit Mode-3 V to +8 VVHDCPLDo not connect except for capacitor to VccVLDCPLDo not connect except for capacitor to VEEQH, QH, QL, QL Maximum Iout50 mAContinuous50 mASurge100 mATHERM0 V to 13 VIOHRTN, IOLRTN-3.5 V to +8.5 VVCOMS Short-Circuit Duration3 sec1Environmental175°C	HCOMP, LCOMP to Vout	±10 V			
Vout Inhibit Mode-3 V to +8 VVHDCPLDo not connect except for capacitor to VccVLDCPLDo not connect except for capacitor to VEEQH, QH, QL, QL Maximum lout50 mAContinuous50 mASurge100 mATHERM0 V to 13 VIOHRTN, IOLRTN-3.5 V to +8.5 VVCOMS Short-Circuit Duration3 sec1Environmental175°C	Outputs				
VHDCPLDo not connect except for capacitor to VccVLDCPLDo not connect except for capacitor to VccQH, QH, QL, QL Maximum lout50 mAContinuous50 mASurge100 mATHERM0 V to 13 VIOHRTN, IOLRTN-3.5 V to +8.5 VVCOMS Short-Circuit Duration3 sec1Environmental175°C	Vout Short-Circuit Duration	Indefinite ¹			
VLDCPLfor capacitor to VccVLDCPLDo not connect except for capacitor to VEEQH, QH, QL, QL Maximum lout50 mAContinuous50 mASurge100 mATHERM0 V to 13 VIOHRTN, IOLRTN-3.5 V to +8.5 VVCOMS Short-Circuit Duration3 sec1Environmental0perating Temperature (Junction)175°C	Vout Inhibit Mode	-3 V to +8 V			
QH, QH, QL, QL Maximum Ioutfor capacitor to VEEQH, QH, QL, QL Maximum Iout50 mAContinuous50 mASurge100 mATHERM0 V to 13 VIOHRTN, IOLRTN-3.5 V to +8.5 VVCOMS Short-Circuit Duration3 sec1Environmental175°C	VHDCPL				
Continuous50 mASurge100 mATHERM0 V to 13 VIOHRTN, IOLRTN-3.5 V to +8.5 VVCOMS Short-Circuit Duration3 sec1Environmental	VLDCPL				
Surge100 mATHERM0 V to 13 VIOHRTN, IOLRTN-3.5 V to +8.5 VVCOMS Short-Circuit Duration3 sec1Environmental175°C	QH, QH, QL, QL Maximum lout				
THERM0 V to 13 VIOHRTN, IOLRTN-3.5 V to +8.5 VVCOMS Short-Circuit Duration3 sec1Environmental175°C	Continuous	50 mA			
IOHRTN, IOLRTN-3.5 V to +8.5 VVCOMS Short-Circuit Duration3 sec1Environmental75°C	Surge	100 mA			
VCOMS Short-Circuit Duration3 sec1Environmental0perating Temperature (Junction)175°C	THERM	0 V to 13 V			
Environmental Operating Temperature (Junction) 175°C	IOHRTN, IOLRTN	-3.5 V to +8.5 V			
Operating Temperature (Junction) 175°C	VCOMS Short-Circuit Duration	3 sec ¹			
	Environmental				
	Operating Temperature (Junction)	175°C			
	Storage Temperature Range	–65°C to +150°C			
Lead Temperature (Soldering, 10 sec) ² 260°C	Lead Temperature (Soldering, 10 sec) ²	260℃			

¹ Output short-circuit protection is guaranteed as long as proper heat sinking is employed to ensure compliance with the operating temperature limits. ² To ensure lead coplanarity (± 0.002 inches) and solderability, handling with bare hands should be avoided and the device should be stored in environments at 24°C \pm 5°C (75°F \pm 10°F) with relative humidity not to exceed 65%.

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Table 9. Package Thermal Resistance

Airflow (m/s)	θ _{JA} (°C/W)
0	42.7
1	37.8
2	36.4

For liquid-cooled applications, $\theta_{JC} = 3.0^{\circ}C/W$.

ESD CAUTION



ESD (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

PIN CONFIGURATION AND FUNCTION DESCRIPTIONS



Table 10. Pin Function Descriptions

Pin No.	Mnemonic	Description
1, 34, 51, 52	V _{cc}	Positive Power Supply.
2, 5, 8	VCCO	Comparator Output Power Supply.
3	QL	Comparator Low Output, Inverting.
4	QL	Comparator Low Output, Noninverting.
6	QH	Comparator High Output, Inverting.
7	QH	Comparator High Output, Noninverting.
9, 33, 44, 46, 48	PWRGND	Ground.
10	LEL	Latch Enable Low Input, Inverting.
11	LEL	Latch Enable Low Input, Noninverting.
12	LEH	Latch Enable High Input, Inverting.
13	LEH	Latch Enable High Input, Noninverting.
14, 26	NC	Do not connect.
15	THERM	Temperature Sensor Output.
16	HCOMP	High Comparator Threshold.
17	LCOMP	Low Comparator Threshold.
18	VHDCPL	Connect 39 nF compensation capacitor to VEE.
19	HQGND2	Ground.
20	Vout	DUT Connection.
21	OUT_L	Active Load Output.
22	VLDCPL	Connect 39 nF compensation capacitor to VEE.
23	IOLRTN	Active Load Low Inhibit Control.
24	VCOMS	VCOM Buffer Sense Output.
25	VCOMI	VCOM Input Voltage.
27	IOHRTN	Active Load High Inhibit Control.
28	HQGND	Ground.
29	IOHC	Active Load High Current Control Input.
30	IOLC	Active Load Low Current Control Input.

Pin No.	Mnemonic	Description
31	VL	Low Driver Level.
32, 39, 40, 41	VEE	Negative Power Supply.
35	INHL	Inhibit Load Input, Inverting.
36	INHL	Inhibit Load Input, Noninverting.
37	DATA	Drive Data Input, Noninverting.
38	DATA	Drive Data Input, Inverting.
42	IOD	IO Data Input, Inverting.
43	IOD	IO Data Input, Noninverting.
45	VT	Term Driver Level.
47	V _H	High Driver Level.
49	RLD	V _T /Inhibit Selection Input, Noninverting.
50	RLD	V _T /Inhibit Selection Input, Inverting.

OUTLINE DIMENSIONS



022708-A

Figure 3. 52-Lead Low Profile Quad Flat Package, Exposed Pad [LQFP_EP] (SW-52-1) Dimensions shown in millimeters

ORDERING GUIDE

Model	Temperature Range	Package Description	Package Option	Ordering Quantity
AD53509JSW	0°C to 70°C	52-Lead LQFP_EP	SW-52-1	90
AD53509JSWZ ¹	0°C to 70°C	52-Lead LQFP_EP	SW-52-1	90

 1 Z = RoHS Compliant Part.

NOTES

©2008 Analog Devices, Inc. All rights reserved. Trademarks and registered trademarks are the property of their respective owners. D01539-0-3/08(B)

Rev. B | Page 12 of 12

www.analog.com